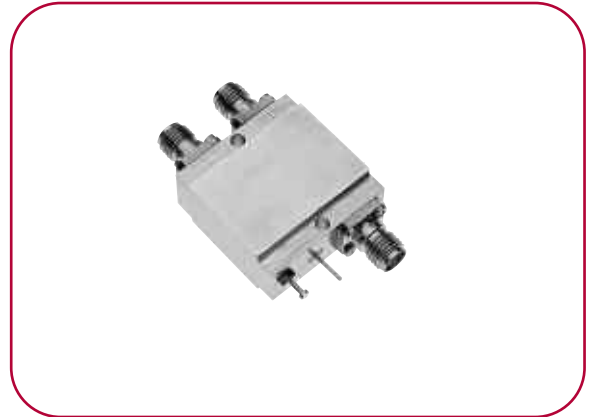


8 TO 10 GHz ULTRA-HIGH LEVEL FET MIXER

MODELS: SBF0810HI3A AND SBF0810HI3B

FEATURES

- RF/LO coverage 8 to 10 GHz
- IF operation 20 to 2000 MHz
- LO power range +20 to +23 dBm
- Input IP³ +33 dBm typical
- Packaging Hermetically sealed



MITEQ's Model SBF0810HI3 utilizes high-level MESFETs in a single-balanced mixer configuration to provide truly state-of-the-art dynamic range performance. Through MITEQ's unique balun design, the SBF0810H Series is able to surpass the performance of any Schottky device by supporting 10 dB of separation between the LO power and third-order intercept point. Applications for this type of device span any dense signal environment system or any extremely high dynamic receiver, such as a phase coherent receiver utilizing high-gain low-noise amplifiers.

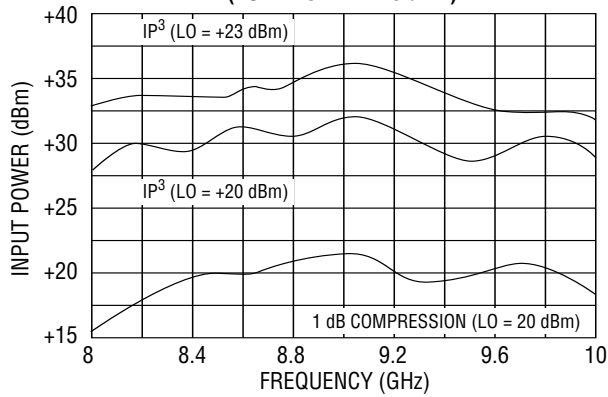
ELECTRICAL SPECIFICATIONS

INPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
RF frequency range		GHz	8		10
RF VSWR (IF = -10 dBm, LO = +23 dBm)		Ratio		2.5:1	
LO frequency range	SBF0810HI3A	GHz	8		10
LO < RF, only	SBF0810HI3B	GHz	6		10
LO power range		dBm	+20		+23
LO VSWR (RF = -10 dBm, LO = +23 dBm)		Ratio		3.5:1	
DC bias -12 VDC		mA		25	
TRANSFER CHARACTERISTICS	CONDITION	UNITS	MIN.	TYP.	MAX.
Conversion loss	IF = 1 GHz	dB		8	9
LO-to-RF isolation		dB	20	30	
LO-to-IF isolation		dB		20	
RF-to-IF isolation		dB		30	
Input power at 1 dB compression	LO = +23 dBm LO = +20 dBm	dBm dBm		+23 +20	
Input two-tone third-order intercept point	LO = +23 dBm LO = +20 dBm	dBm dBm	30	+33 +30	
Input two-tone second-order intercept point	LO = +23 dBm	dBm		+45	
OUTPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
IF frequency range (3 dB bandwidth)	SBF0810HI3A SBF0810HI3B	MHz MHz	200 1400		1200 2000
IF VSWR (IF = -10 dBm, LO = +23 dBm)		Ratio		2:1	

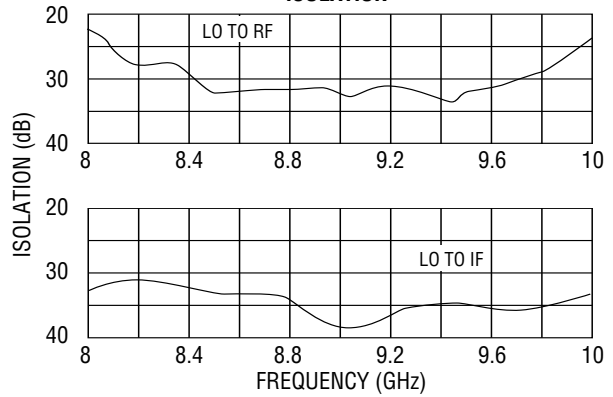


SBF0810HI3A/B TYPICAL TEST DATA

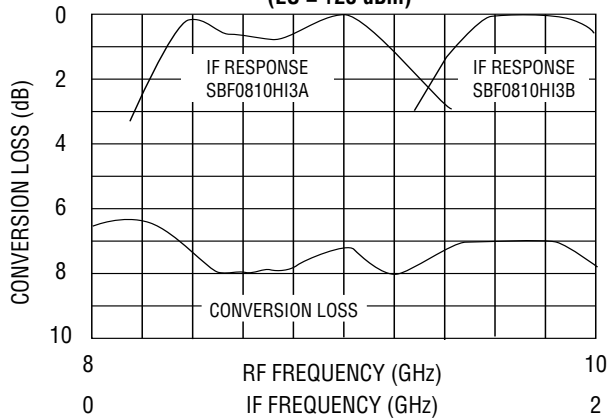
**INPUT IP³ AND P 1 dB COMPRESSION
(LO = +20 AND +23 dBm)**



ISOLATION



**CONVERSION LOSS IF RESPONSE
(LO = +23 dBm)**



**SINGLE-TONE (m) RF x (n) LO RELATIVE SPUR LEVEL (dBc)
(RF = 0 dBm, LO = +23 dBm)**

(m) RF	x	(n) LO	SPUR LEVEL (dBc)
2	x	2	-50
3	x	3	-65
3	x	4	-70
4	x	5	-90
5	x	6	-100
6	x	7	-130
6	x	8	-135
7	x	8	-155
7	x	9	-150
8	x	9	-170

MAXIMUM RATINGS

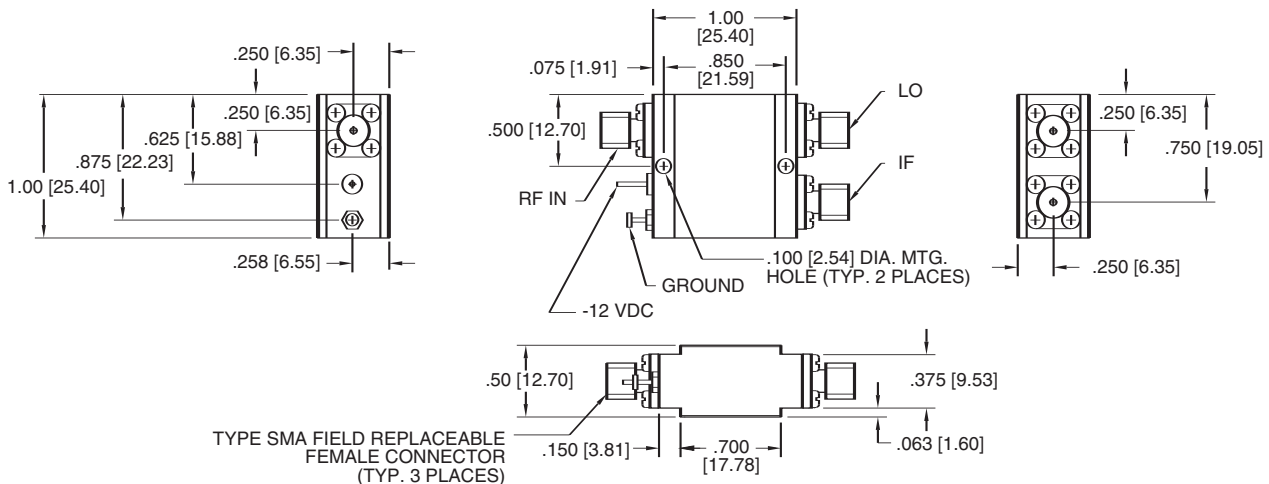
Specification temperature..... +25°C
 Operating temperature -54 to +85°C
 Storage temperature -65 to +125°C

AVAILABLE OPTIONS

Alternate LO drive levels.
 Alternate RF and IF frequencies.
 Open substrate carrier versions.

NOTE: Test data supplied at 25°C; conversion loss, LO-to-RF isolation and IP³.

OUTLINE DRAWING



NOTE: All dimensions shown in brackets [] are in millimeters.

